

TENTATIVE

TLP748J

- Office Machine
- Household Use Equipment
- Solid State Relay
- Switching Power Supply

The TOSHIBA TLP748J consists of a photo-thyristor optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

- Peak off-state voltage: 600 V (min.)
- Trigger LED current: 10 mA (max.)
- On-state current: 150 mA (max.)
- UL recognized (scheduled): UL1577, file no. E67349
- BSI approved (scheduled): BS EN60065

BS EN60950:

- SEMKO approved (scheduled): SS4330784,
SS-EN60950
- Isolation voltage: 4000 Vrms (min.)
- Option (D4) type
VDE approved (scheduled): DIN EN 60747-5-2

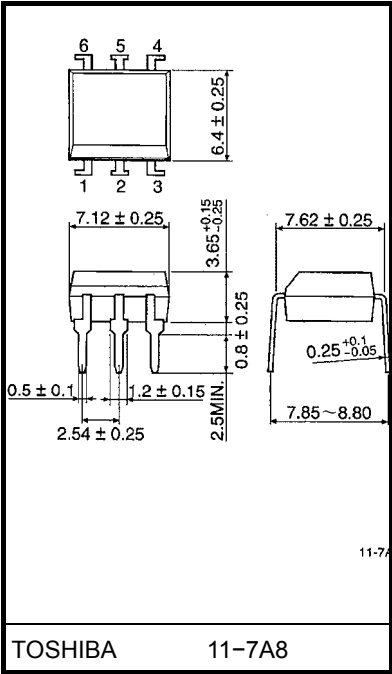
Maximum operating insulation voltage: 630 V_{pk} , 890 V_{pk}

Highest permissible over voltage: 6000 V_{pk} , 8000 V_{pk}

(Note) When a EN 60747-5-2 approved type is needed, please designate the “option (D4)”

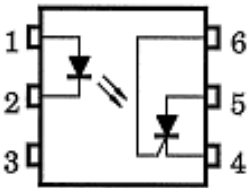
	7.62 mm pich standard type	10.16 mm pich (LF2) type
• Creepage distance:	7.0 mm (min.)	8.0 mm (min.)
Clearance:	7.0 mm (min.)	8.0 mm (min.)
Insulation thickness:	0.5 mm (min.)	0.5 mm (min.)

Unit in mm



Weight: 0.42g

Pin Configuration (top view)



- 1 : ANODE
- 2 : CATHODE
- 3 : N.C.
- 4 : CATHODE
- 5 : ANODE
- 6 : GATE

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating ($T_a \geq 39^\circ\text{C}$)	$\Delta I_F / ^\circ\text{C}$	-0.7	mA / $^\circ\text{C}$
	Peak forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse voltage	V_R	5	V
Detector	Peak forward voltage ($R_{GK} = 27 \text{ k}\Omega$)	V_{DRM}	600	V
	Peak reverse voltage ($R_{GK} = 27 \text{ k}\Omega$)	V_{RRM}	600	V
	On-state current	$I_{T(RMS)}$	150	mA
	On-state current derating ($T_a \geq 25^\circ\text{C}$)	$\Delta I_T / ^\circ\text{C}$	-2.0	mA / $^\circ\text{C}$
	Peak on-state current (100 μs pulse, 120 pps)	I_{TP}	3	A
	Peak one cycle surge current	I_{TSM}	2	A
	Peak reverse gate voltage	V_{GM}	5	V
Storage temperature range		T_{stg}	-55~125	$^\circ\text{C}$
Operating temperature range		T_{opr}	-55~100	$^\circ\text{C}$
Lead soldering temperature (10 s)		T_{sol}	260	$^\circ\text{C}$
Isolation voltage (AC, 1 min., R.H. $\leq 60\%$)		BV_S	4000	V_{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V_{AC}	—	—	240	V_{ac}
Forward current	I_F	15	—	25	mA
Operating temperature	T_{opr}	-25	—	85	$^\circ\text{C}$
Gate to cathode resistance	R_{GK}	—	10	27	$\text{k}\Omega$
Gate to cathode capacity	C_{GK}	—	0.01	0.1	μF

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Off-state current	I_{DRM}	$V_{AK} = 600 \text{ V}, R_{GK} = 27 \text{ k}\Omega$	—	—	5	μA
	Reverse current	I_{RRM}	$V_{KA} = 600 \text{ V}, R_{GK} = 27 \text{ k}\Omega$	—	—	5	μA
	On-state voltage	V_{TM}	$I_{TM} = 100 \text{ mA}$	—	—	1.45	V
	Holding current	I_H	$R_{GK} = 27 \text{ k}\Omega$	—	—	1	mA
	Off-state dv / dt	dv / dt	$V_{AK} = 420 \text{ V}, R_{GK} = 27 \text{ k}\Omega$	5	—	—	V/ μs
	Capacitance	C_j	$V = 0, f = 1 \text{ MHz}$			—	pF
			Anode to gate	—	—		
			Gate to cathode	—	—	—	

Coupled Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Trigger LED current	I_{FT}	$V_{AK} = 6 \text{ V}, R_{GK} = 27 \text{ k}\Omega$	—	—	10	mA
Turn-on time	t_{ON}	$I_F = 30 \text{ mA}, V_{AA} = 50 \text{ V}$ $R_{GK} = 27 \text{ k}\Omega$	—	—	—	μs
Capacitance (input to output)	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}$	1×10^{12}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 minute	4000	—	—	V_{rms}
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	V_{dc}

RESTRICTIONS ON PRODUCT USE

20070701-EN

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
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